

Product Summary

- V_{DS} 30 V
- I_D 30 A
- $R_{DS(ON)}$ (at $V_{GS}= 10V$) Typ 10 mohm
- $R_{DS(ON)}$ (at $V_{GS}= 4.5V$) Typ 15mohm
- 100% UIS Tested
- 100% ∇V_{DS} Tested

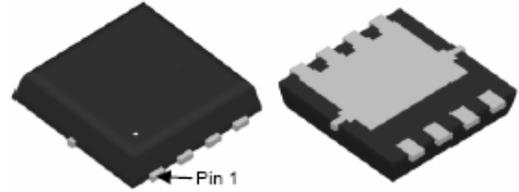
General Description

- Trench Power LV MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$

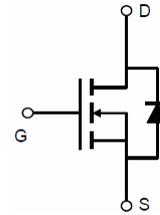
Applications

- High current load applications
- Load switching
- Hard switched and high frequency circuits
- Uninterruptible power supply

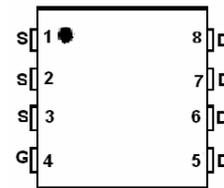
DFN3X3-8 Pin Configuration



Schematic Diagram



pin assignment



Absolute Maximum Ratings ($T_A=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	V_{DS}	30	V
Gate-source Voltage	V_{GS}	± 20	V
Drain Current	I_D	$T_C=25^{\circ}C$	30
		$T_C=100^{\circ}C$	15
Pulsed Drain Current ^A	I_{DM}	70	A
Single Pulse Avalanche Energy ^B	E_{AS}	19	mJ
Total Power Dissipation	$T_C=25^{\circ}C$	P_D	12 W
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	6.0	$^{\circ}C/W$
Thermal Resistance Junction-to-ambient	$R_{\theta JA}$	40	$^{\circ}C/W$
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^{\circ}C$

Ordering Information (Example)

PREFERED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
LX38F30N30C	F1		5000	10000	100000	13" reel



Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	30			V
Zero Gate Voltage Drain Current	I_{BSS}	$V_{DS}=30V, V_{GS}=0V$			1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}= \pm 20V, V_{DS}=0V$			± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.5	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=15A$		10	14	m Ω
		$V_{GS}=4.5V, I_D=10A$		15	21	
Diode Forward Voltage	V_{SD}	$I_S=12A, V_{GS}=0V$		0.85	1.2	V
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V, f=1\text{MHz}$		3851		pF
Output Capacitance	C_{oss}			444		
Reverse Transfer Capacitance	C_{rss}			316		
Switching Parameters						
Total Gate Charge	Q_g	$V_{GS}=4.5V, V_{DS}=10V, I_D=20A$		45.3		nC
Gate-Source Charge	Q_{gs}			7.5		
Gate-Drain Charge	Q_{gd}			11.1		
Reverse Recovery Charge	Q_{rr}	$I_F=20A, di/dt=100A/\mu s$		6.9		ns
Reverse Recovery Time	t_{rr}			27		
Turn-on Delay Time	$t_{D(on)}$	$V_{GS}=4.5V, V_{DD}=10V, R_L=0.5\Omega, R_{GEN}=3\Omega$		22		ns
Turn-on Rise Time	t_r			107		
Turn-off Delay Time	$t_{D(off)}$			86		
Turn-off fall Time	t_f			115		

A. Pulse Test: Pulse Width $\leq 300\mu s$, Duty cycle $\leq 2\%$.

B. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

Typical Performance Characteristics

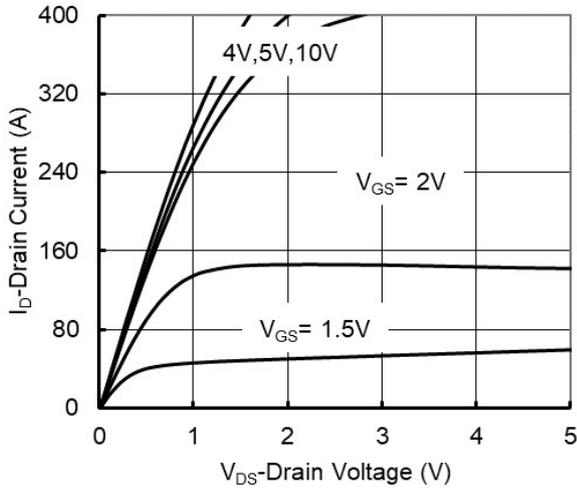


Figure 1. Output Characteristics

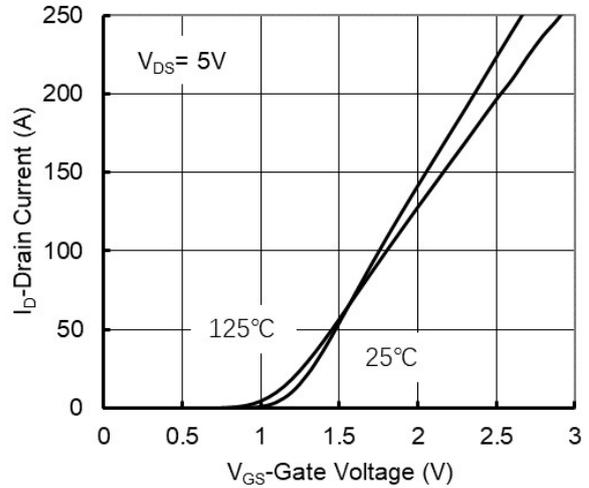


Figure 2. Transfer Characteristics

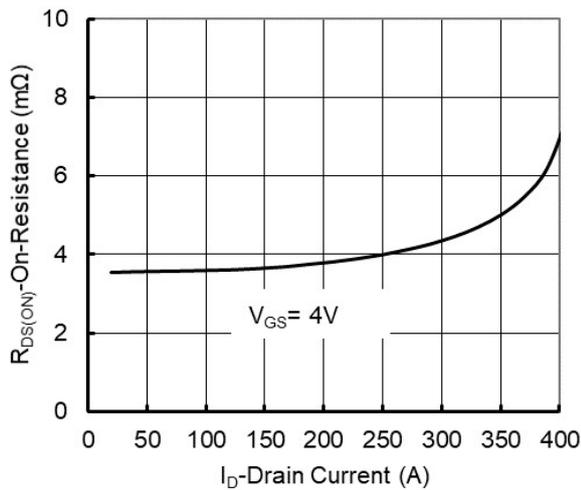


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

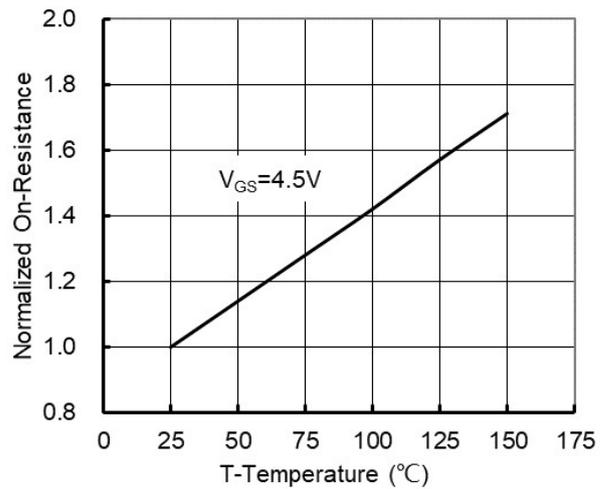


Figure 4. On-Resistance vs. Junction Temperature

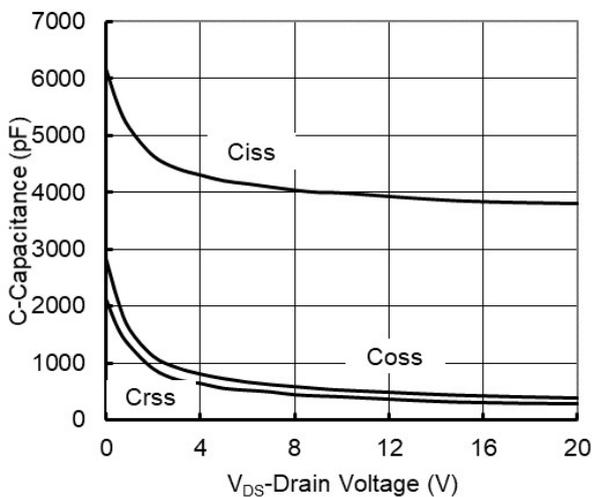


Figure 5. Capacitance Characteristics

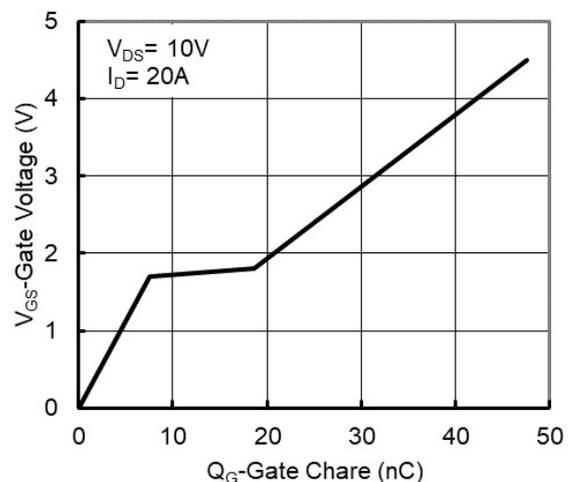


Figure 6. Gate Charge

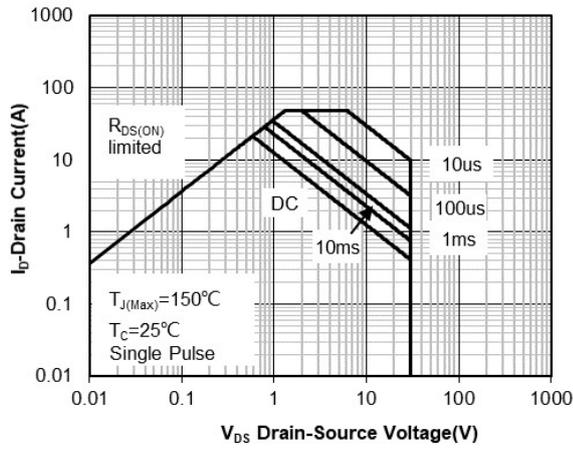


Figure 7. Safe Operation Area

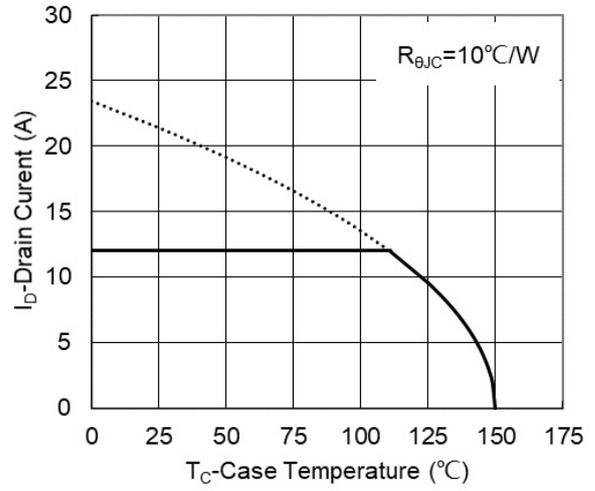


Figure 8. Maximum Continuous Drain Current vs Case Temperature

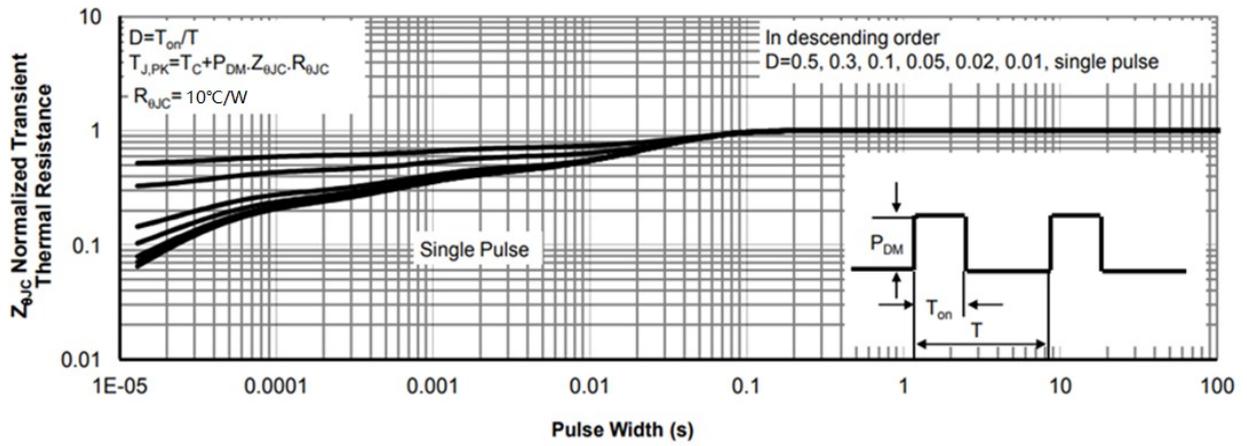
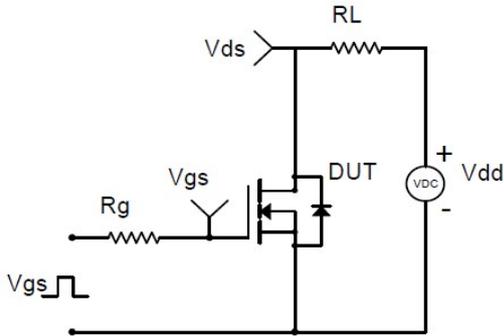
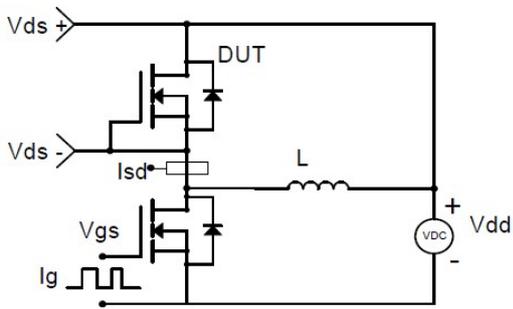
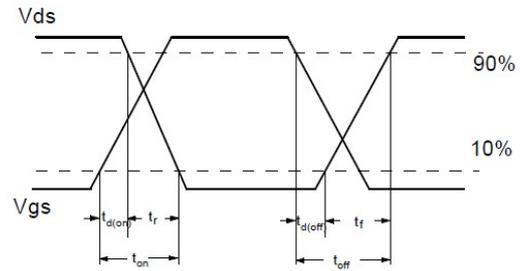


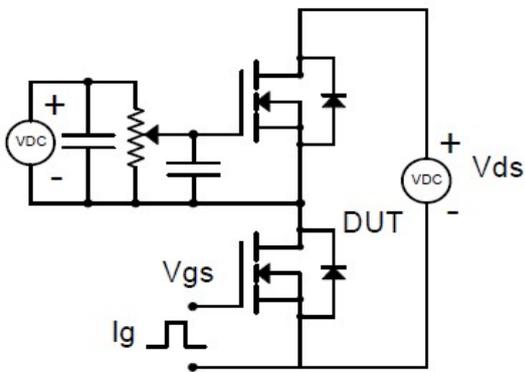
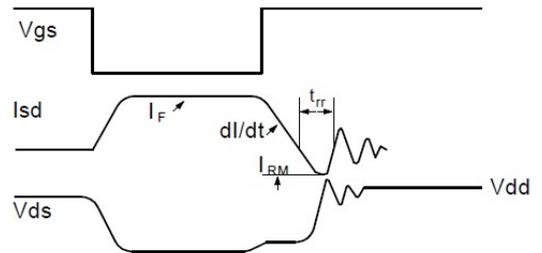
Figure 9. Normalized Maximum Transient Thermal Impedance



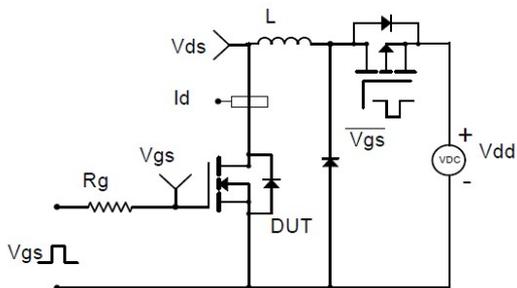
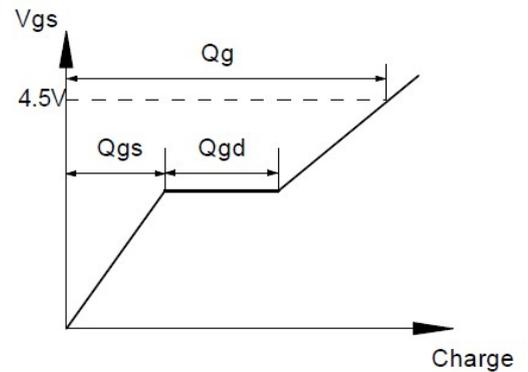
Resistive Switching Test Circuit & Waveforms



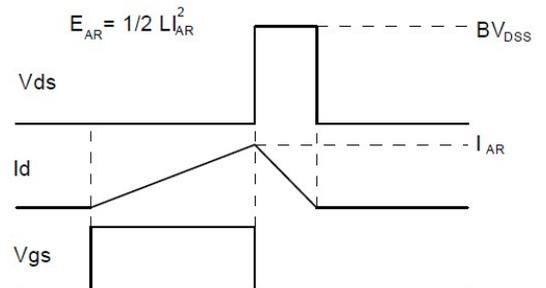
Diode Recovery Test Circuit & Waveforms



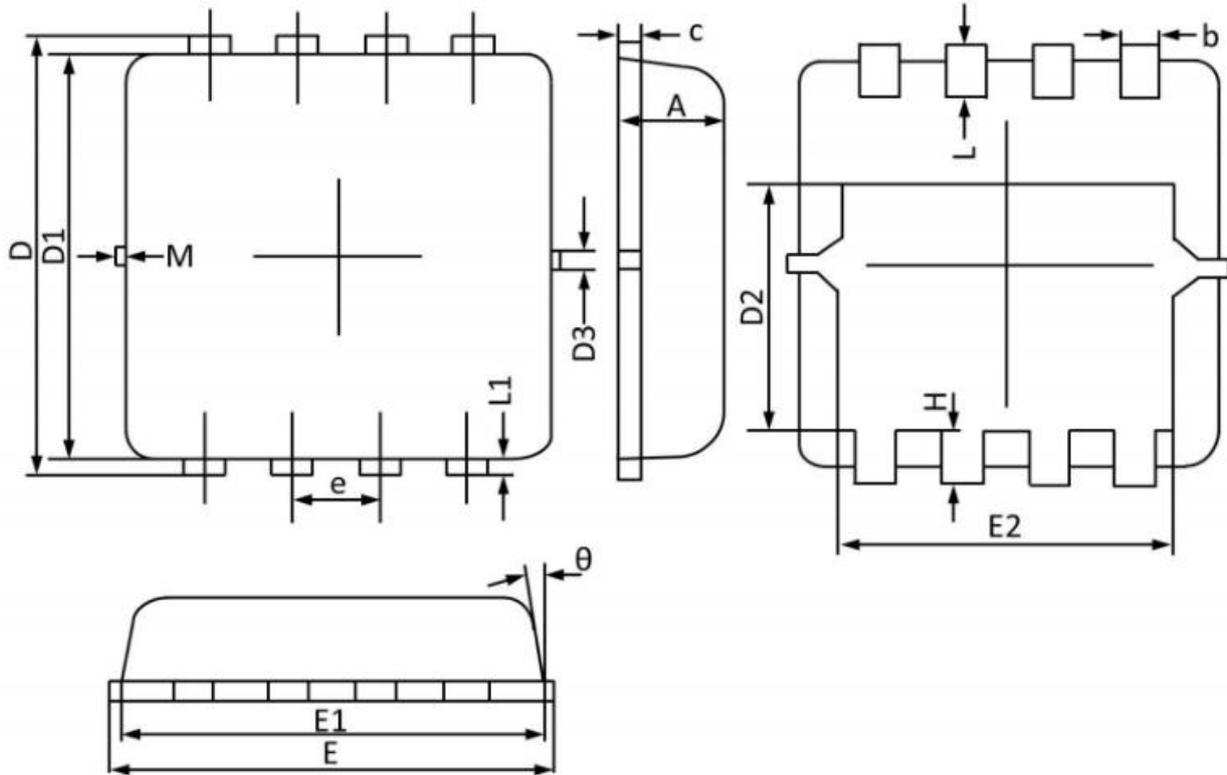
Gate Charge Test Circuit & Waveform



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



PDFN3*3-8L Package Out line Dimensions



DIMENSIONS (unit : mm)

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
A	0.70	0.79	0.9	b	0.25	0.30	0.4
C	0.10	0.15	0.25	D	3.15	3.30	3.45
D1	2.90	3.05	3.20	D2	1.63	1.77	1.93
D3	--	0.13	--	E	3.15	3.30	3.40
E1	3.00	3.15	3.20	E2	2.30	2.45	2.60
e	0.65BSC			H	0.30	0.39	0.50
L	0.30	0.40	0.50	L1	--	0.13	--
theta	--	10°	12°	M	-	-	0.15